

MJD31C

Low voltage NPN power transistor

Datasheet – production data

Features

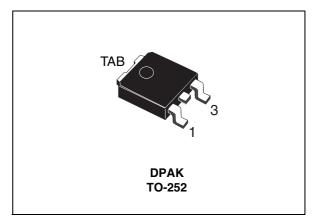
- Surface-mounting TO-252 power package in tape and reel
- Complementary to the PNP type MJD32C

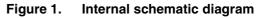
Application

 General purpose linear and switching equipment

Description

The device is manufactured in planar technology with "base island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.





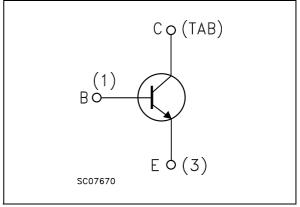


Table 1. Device summary

Order code	Marking	Package	Packaging
MJD31CT4	MJD31C	DPAK	Tape and reel

Doc ID 3543 Rev 5

This is information on a product in full production.

1 Electrical ratings

Table 2.	Absolute	maximum	ratings
	Absolute	maximum	raungs

Symbol	Parameter	Value	Unit				
V _{CBO}	Collector-base voltage ($I_E = 0$)	100	V				
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	100	V				
V _{EBO}	Emitter-base voltage ($I_{C} = 0$)	5	V				
Ι _C	Collector current	3	А				
I _{CM}	Collector peak current	5	А				
Ι _Β	Base current	1	А				
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	15	W				
T _{STG}	Storage temperature	-65 to 150	°C				
TJ	Max. operating junction temperature	150	°C				

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	8.3	°C/W
R _{thJPCB} ⁽¹⁾ Thermal resistance junction-pcb max		50	°C/W

1. When mounted on FR-4 board of 1 inch², 2 oz Cu.



2 Electrical characteristics

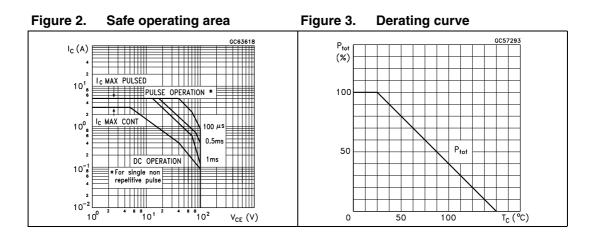
 T_{case} = 25 °C unless otherwise specified.

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 100 V			-	20	μA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CB} = 60 V			-	50	μA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V			-	0.1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C = 30 mA		100	-		v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 3 A	l _B = 375 mA		-	1.2	v
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	I _C = 3 A	$V_{CE} = 4 V$		-	1.8	V
h _{FE}	DC current gain	$I_{\rm C} = 1 \text{ A}$ $I_{\rm C} = 3 \text{ A}$	V _{CE} = 4 V V _{CE} = 4 V	25 10	-	50	

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %

2.1 Electrical characteristic (curves)





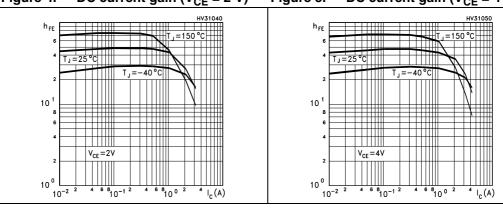
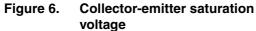


Figure 4. DC current gain (V_{CE} = 2 V) Figure 5. DC current gain (V_{CE} = 4 V)



++++++

T_J =150 °C

h_{FE} =10

4 6 8

10°

1_c (A)

T_J=25°C, -40°C

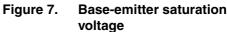
V_{CE (sat)} (V) 6

10⁰

10

10⁻²

10⁻²



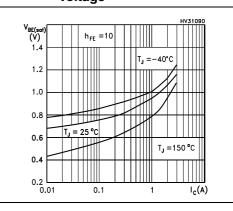
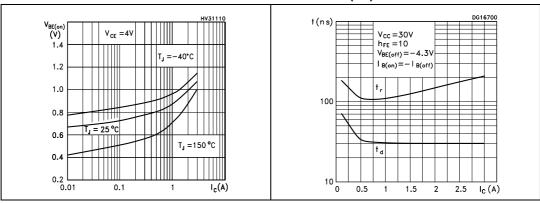


Figure 8. **Base-emitter on voltage**

⁶ ⁸ 10⁻¹ ²

Figure 9. **Resistive load switching time** (on)

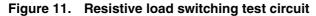


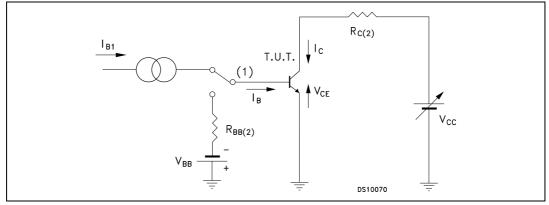


(off) $t(n s) = 10^{10} t(n s) + t(n s$

Figure 10. Resistive load switching time (off)

2.2 Test circuits





- 1. Fast electronic switch
- 2. Non-inductive resistor



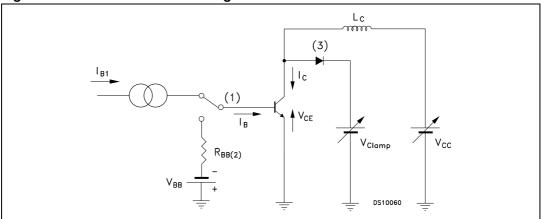
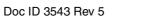


Figure 12. Inductive load switching test circuit

- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier



3 Package mechanical data

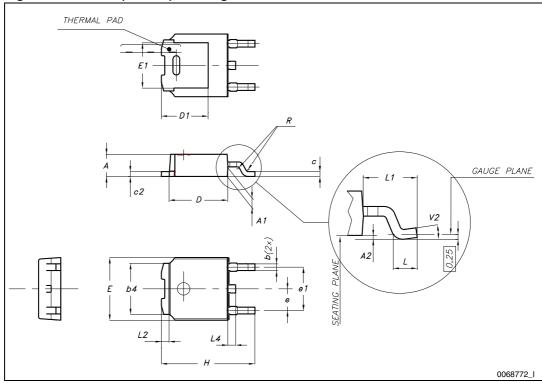
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

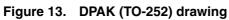


Table 5.	DPAK (TO-252) mechanical data

Dim.	× /	mm	
	Min.	Тур.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
с	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
н	9.35		10.10
L	1		1.50
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°





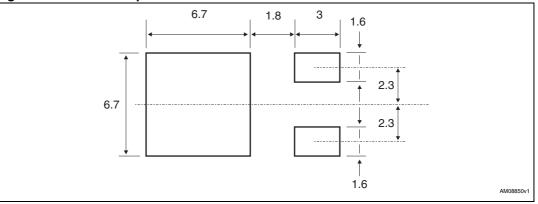




	Таре			Reel		
Dim.	n	nm	Dim.	mm		
Dini.	Min.	Max.		Min.	Max.	
A0	6.8	7	А		330	
B0	10.4	10.6	В	1.5		
B1		12.1	С	12.8	13.2	
D	1.5	1.6	D	20.2		
D1	1.5		G	16.4	18.4	
Е	1.65	1.85	N	50		
F	7.4	7.6	Т		22.4	
K0	2.55	2.75				
P0	3.9	4.1		Base qty.	2500	
P1	7.9	8.1		Bulk qty.	2500	
P2	1.9	2.1				
R	40					
Т	0.25	0.35				
W	15.7	16.3				

 Table 6.
 DPAK (TO-252) tape and reel mechanical data

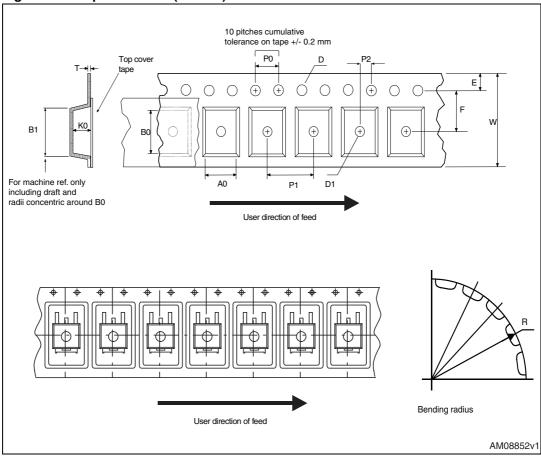
Figure 14. DPAK footprint^(a)



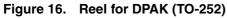
a. All dimensions are in millimeters

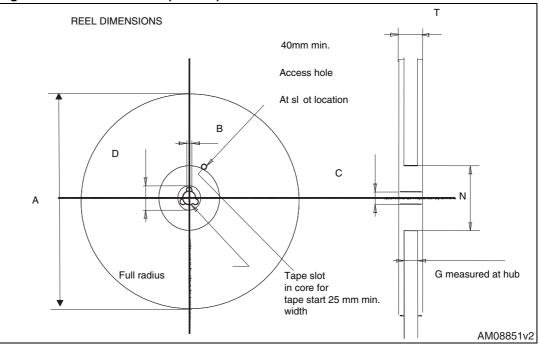
Doc ID 3543 Rev 5













4 Revision history

Table 7.Document revision history

Date	Revision	Changes
01-Dec-2000	1	Initial release.
20-Apr-2007	2	Added new graphics.
09-Nov-2009	3	Updated package mechanical data.
14-Jan-2010	4	Modified Table 3 on page 2.
19-Jun-2012	5	Updated: mechanical data



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2012 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



Doc ID 3543 Rev 5